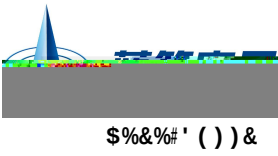


#*# +, -./, 0#1, 2310#

			625 mW 300mW		



##*##\$, /21.A<.3=/#

□ Silicon PNP transistor in a SOT-23 Plastic Package.

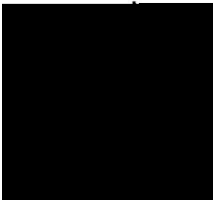
##*##7, :<B1, /#

Complementary pair with L8050M.

##*##%AA9.2:<.3=/##

Power amplifier applications.

##*##)CB.-:9,=<#8.12B.<#



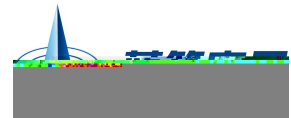
##*##D.==.=@#



PIN1 Base PIN 2 Emitter PIN 3 Collector

##*##67)#89: / / .; .2:<.3=/#>#" :1?.=@#

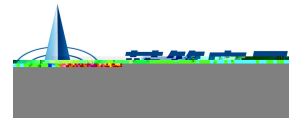
h_{FE}



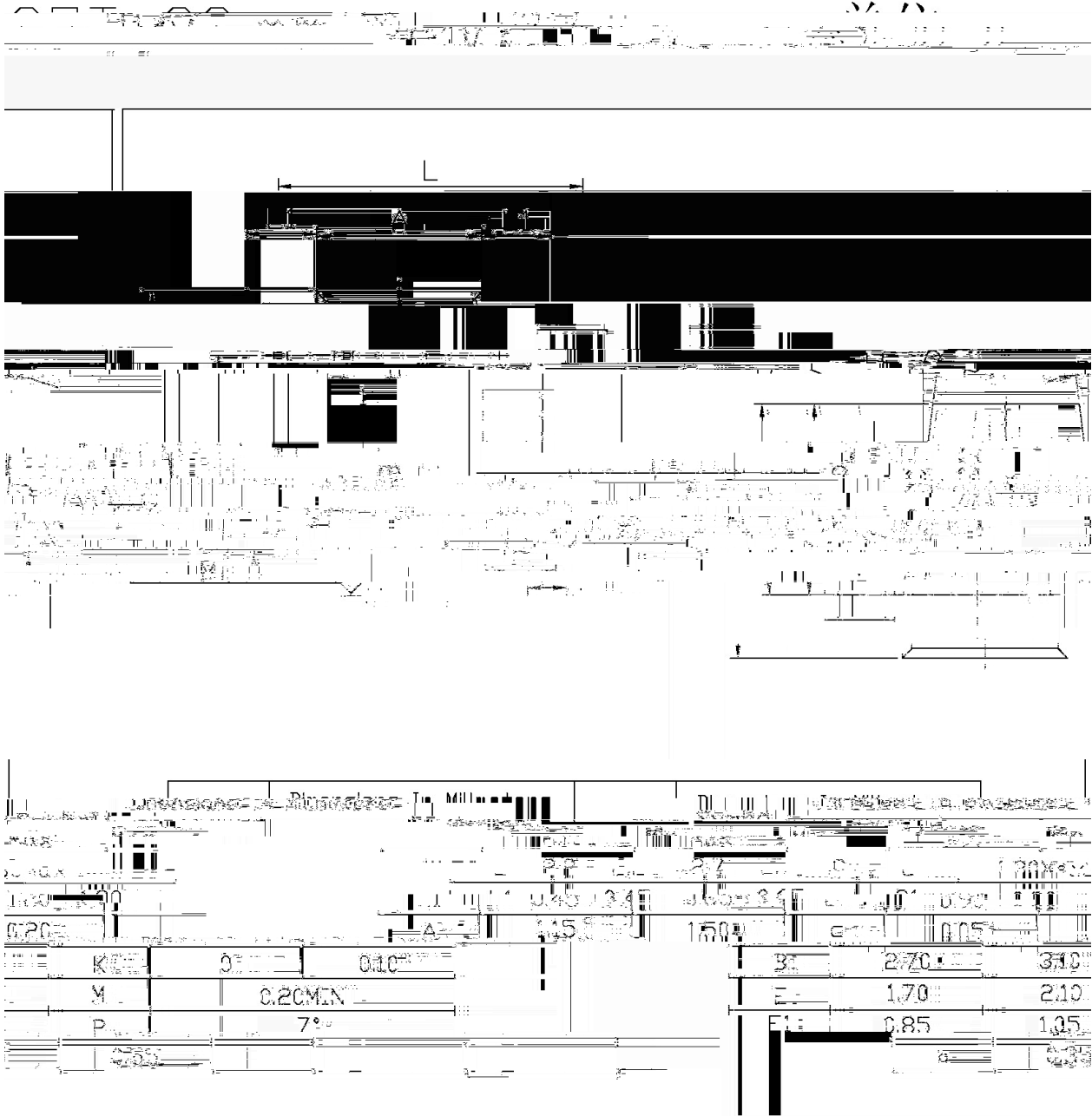
#

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-30	V
Collector to Emitter Voltage	V_{CEO}	-20	V
Emitter to Base Voltage	V_{EBO}	-6.0	V
Collector Current - Continuous	I_C	-1.5	A
Base Current - Continuous	I_B	-0.5	A
Collector Po/ $\bar{\tau}$ $\bar{L}$ Dissi	$\bar{\tau}$	o	n

Ū

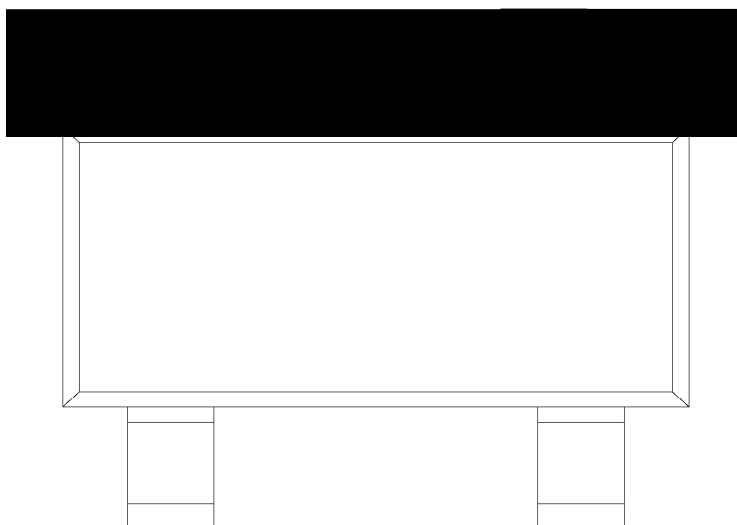


###D:2?:@,\$. I , = / .3 = / #



##*## " :1?=@#N= /<1B2<.3= /#

0



J L# #*## Temperature Profile for IR Reflow Soldering(Pb-Free)

说明：
1、预热温度 150 ~ 180 ，时间 60 ~ 90sec;
2、峰值温度 245±5 ，时间持续为 5±0.5sec;

Note:
1.Preheating:150~180°C, Time:60~90sec.
2.Peak Temp.:245